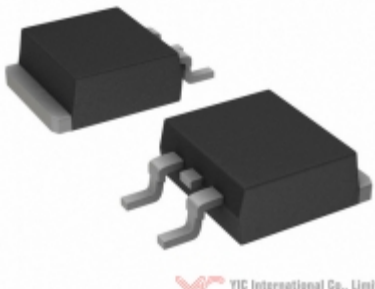

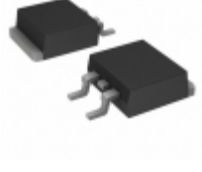







	<h2 style="color: red;">FGB5N60UNDF</h2>
	<p>Hersteller-Teilenummer: FGB5N60UNDF</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: IGBT 600V 10A 73.5W D2PAK</p> <hr/> <p>Datenblätter:  FGB5N60UNDF.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 6760 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FGB5N60UNDF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	IGBT 600V 10A 73.5W D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs-
Teilstatus	6760 pcs Stock
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	73.5W
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	TO-263AB (D ² PAK)
Rückwärts-Erholzeit (Trr)	35ns
Strom - Kollektor (Ic) (max)	10A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	NPT
VCE (on) (Max) @ Vge, Ic	2.4V @ 15V, 5A
Strom - Collector Pulsed (Icm)	15A
Schaltenergie	80µJ (on), 70µJ (off)
Gate-Ladung	12.1nC
Td (ein / aus) bei 25 ° C	5.4ns/25.4ns
Testbedingung	400V, 5A, 10 Ohm, 15V
Verpackung	Tube









FGB5N60UNDF ist neu im Original, Suche FGB5N60UNDF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FGB5N60UNDF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FGB5N60UNDF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FGB7N60UNDF AMI Semiconductor / ON Semiconductor IGBT 600V 14A 83W D2PAK</p>	 <p>FGB40N6S2T AMI Semiconductor / ON Semiconductor IGBT 600V 75A 290W TO263AB</p>	 <p>FGBS3040E1-F085 AMI Semiconductor / ON Semiconductor IC IGNITION COIL DRIVER D2PAK</p>	 <p>FGB40N6S2 Fairchild/ON Semiconductor IGBT 600V 75A 290W TO263AB</p>
 <p>FGB40T65SPD_F085 Fairchild/ON Semiconductor IGBT FIELD STOP 650V 80A D2PAK</p>	 <p>FGB40N6S2 AMI Semiconductor / ON Semiconductor IGBT 600V 75A 290W TO263AB</p>	 <p>FGB5N60UNDF AMI Semiconductor / ON Semiconductor IGBT 600V 10A 73.5W D2PAK</p>	 <p>FGB40N6S2 Fairchild/ON Semiconductor IGBT 600V 75A 290W TO263AB</p>

heiße Teile

Mehr

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 FB15R06YE3-B1	 FGB20N60SF	 FGB20N60SF	 FGB20N60SFD	 FGB20N60SFD
 D FGB20N6S2T	 FGB3040CS	 FGB3040CS	 FGB3040CS_F085	 FGB3040E1
 FGB3040G2	 FGB3040G2-F085	 FGB3040G2_F085	 FGB3056_F085	 FGB30N6S2
 FGB30N6S2	 FGB30N6S2D	 D FGB30N6S2D	 FGB40N60SM	 FGB40N60SM
 FGB40N6S2	 D FGB40N6S2	 FGB5N60UNDF	 HSC1008-10NJ-T	 IPS7091R
 IRFH8324TR2PBF	 KSM-713TC5	 LQH31MN2R7J03L	 MA4ZD030	 MCD312-12I01B
 N260CH34C	 NLAST9431MTR2G	 NRF52832-CIAA	 PS21246-AEP	 PS7241E-1A-F3-A
 SY89873LMGTR	 TC58BVG1S3HTA00	 TLV70030DCKRG4	 TSH692IDT	 UMK105CG390JV-F

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